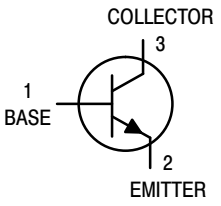
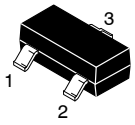
General Purpose Transistors
NPN Silicon

BC846ALT1G Series





SOT-23
CASE 318
STYLE 6

Features

- Moisture Sensitivity Level: 1
- ESD Rating - Human Body Model: > 4000 V
  - Machine Model: > 400 V
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC846 BC847, BC850 BC848, BC849	V_{CEO}	 65 45 30	Vdc
Collector-Base Voltage BC846 BC847, BC850 BC848, BC849	V_{CBO}	 80 50 30	Vdc
Emitter-Base Voltage BC846 BC847, BC850 BC848, BC849	V_{EBO}	 6.0 6.0 5.0	Vdc
Collector Current - Continuous	I_C	100	mAdc

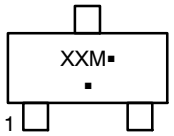
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T_A = 25 °C Derate above 25 °C	P_D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2) T_A = 25 °C Derate above 25 °C	P_D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	°C

1. FR-5 = 1.0 × 0.75 × 0.062 in.
2. Alumina = 0.4 × 0.3 × 0.024 in 99.5% alumina.

MARKING DIAGRAM



XX = Device Code
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 12.

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ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector - Emitter Breakdown Voltage (I_C = 10 mA)	BC846A, B, C	$V_{(BR)CEO}$	65	-	-	V
	BC847A, B, C, BC850B, C		45	-	-	
	BC848A, B, C, BC849B, C		30	-	-	
Collector - Emitter Breakdown Voltage (I_C = 10 μA, V_{EB} = 0)	BC846A, B, C	$V_{(BR)CES}$	80	-	-	V
	BC847A, B, C BC850B, C		50	-	-	
	BC848A, B, C, BC849B, C		30	-	-	
Collector - Base Breakdown Voltage (I_C = 10 μA)	BC846A, B, C	$V_{(BR)CBO}$	80	-	-	V
	BC847A, B, C, BC850B, C		50	-	-	
	BC848A, B, C, BC849B, C		30	-	-	
Emitter - Base Breakdown Voltage (I_E = 1.0 μA)	BC846A, B, C	$V_{(BR)EBO}$	6.0	-	-	V
	BC847A, B, C, BC850B, C		6.0	-	-	
	BC848A, B, C, BC849B, C		5.0	-	-	
Collector Cutoff Current (V_{CB} = 30 V)		I_{CBO}	-	-	15	nA
(V_{CB} = 30 V, T_A = 150°C)			-	-	5.0	μA
ON CHARACTERISTICS						
DC Current Gain	BC846A, BC847A, BC848A	h_{FE}	-	90	-	-
(I_C = 10 μA, V_{CE} = 5.0 V)	BC846B, BC847B, BC848B		-	150	-	
	BC846C, BC847C, BC848C		-	270	-	
(I_C = 2.0 mA, V_{CE} = 5.0 V)	BC846A, BC847A, BC848A		110	180	220	
	BC846B, BC847B, BC848B, BC849B, BC850B		200	290	450	
	BC846C, BC847C, BC848C, BC849C, BC850C		420	520	800	
Collector - Emitter Saturation Voltage (I_C = 10 mA, I_B = 0.5 mA)		$V_{CE(sat)}$	-	-	0.25	V
(I_C = 100 mA, I_B = 5.0 mA)			-	-	0.6	
Base - Emitter Saturation Voltage (I_C = 10 mA, I_B = 0.5 mA)		$V_{BE(sat)}$	-	0.7	-	V
(I_C = 100 mA, I_B = 5.0 mA)			-	0.9	-	
Base - Emitter Voltage (I_C = 2.0 mA, V_{CE} = 5.0 V)		$V_{BE(on)}$	580	660	700	mV
(I_C = 10 mA, V_{CE} = 5.0 V)			-	-	770	
SMALL-SIGNAL CHARACTERISTICS						
Current - Gain - Bandwidth Product (I_C = 10 mA, V_{CE} = 5.0 Vdc, f = 100 MHz)		f_T	100	-	-	MHz
Output Capacitance (V_{CB} = 10 V, f = 1.0 MHz)		C_{obo}	-	-	4.5	pF
Noise Figure (I_C = 0.2 mA, V_{CE} = 5.0 Vdc, R_S = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz)	BC846A,B,C, BC847A,B,C, BC848A,B,C	NF	-	-	10	dB
	BC849B,C, BC850B,C		-	-	4.0	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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BC846A, BC847A, BC848A, SBC846A

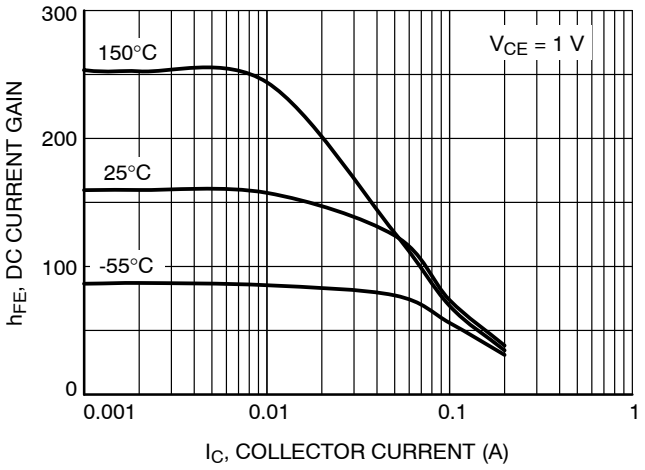

Figure 1. DC Current Gain vs. Collector Current

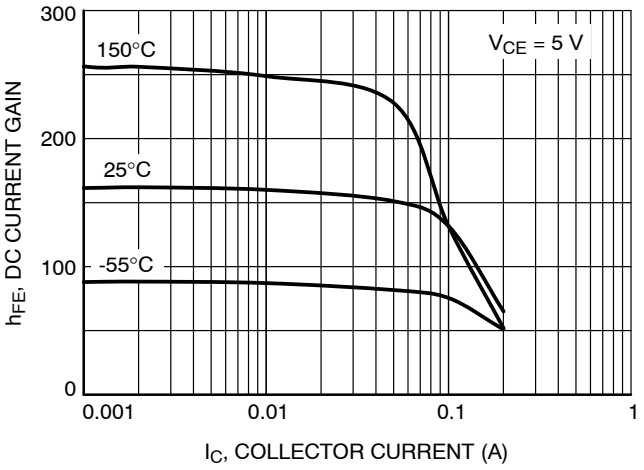

Figure 2. DC Current Gain vs. Collector Current

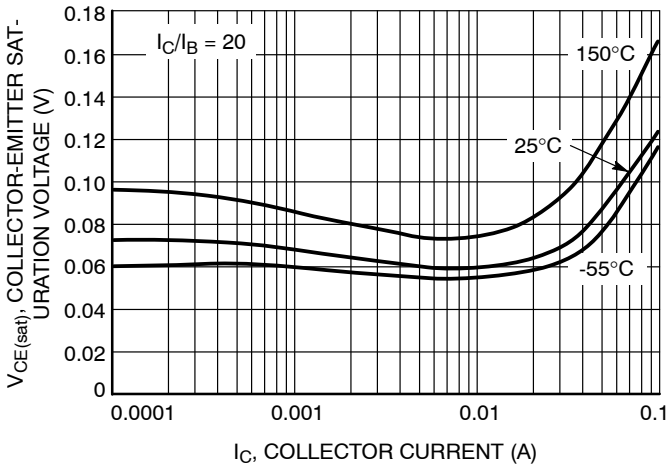

Figure 3. Collector Emitter Saturation Voltage vs. Collector Current

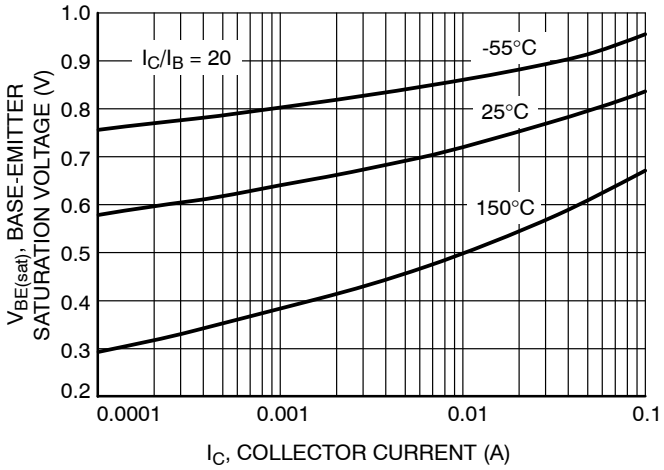

Figure 4. Base Emitter Saturation Voltage vs. Collector Current

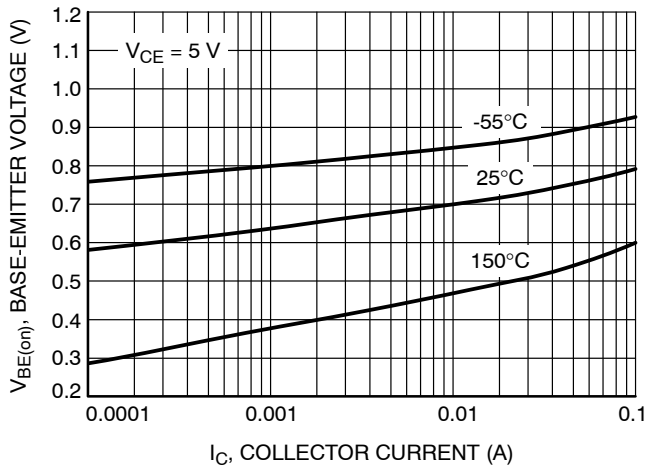

Figure 5. Base Emitter Voltage vs. Collector Current

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BC846A, BC847A, BC848A, SBC846A

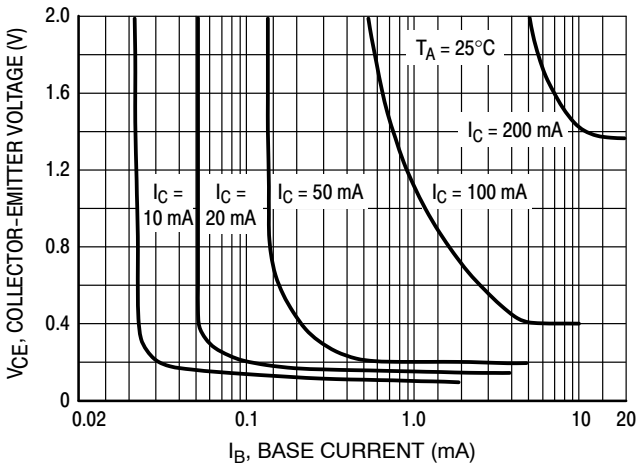

Figure 6. Collector Saturation Region

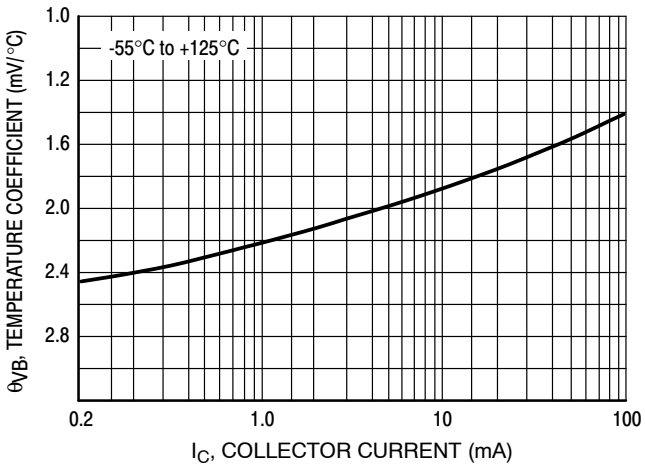

Figure 7. Base-Emitter Temperature Coefficient

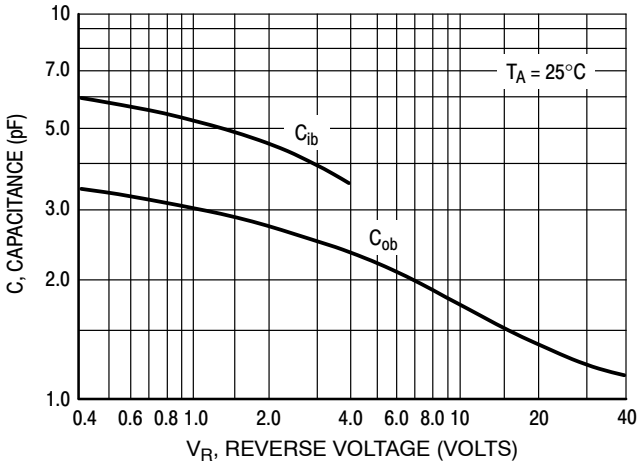

Figure 8. Capacitances

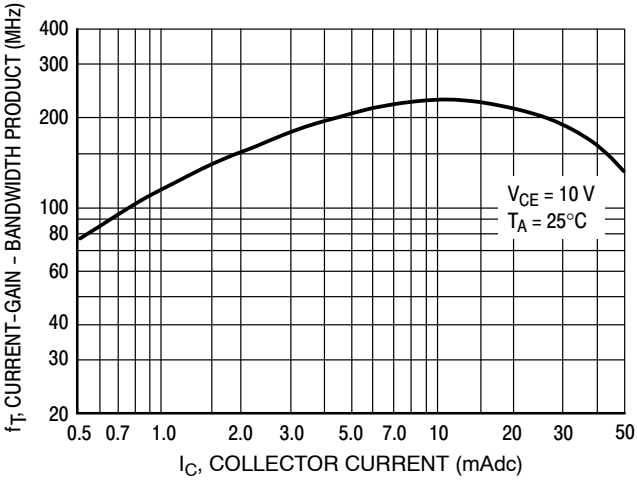

Figure 9. Current-Gain - Bandwidth Product

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BC846B, SBC846B

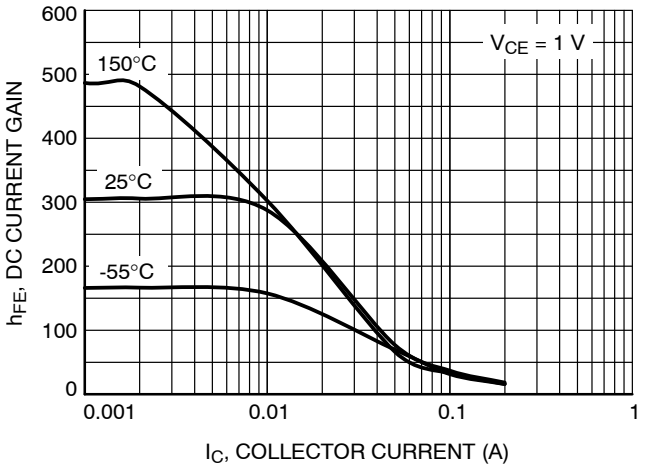

Figure 10. DC Current Gain vs. Collector Current

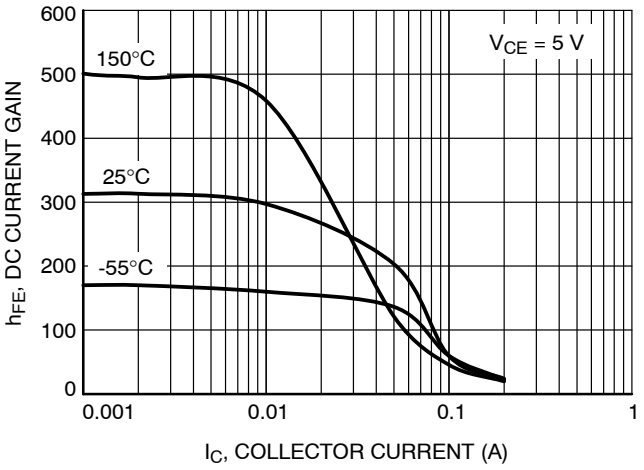

Figure 11. DC Current Gain vs. Collector Current

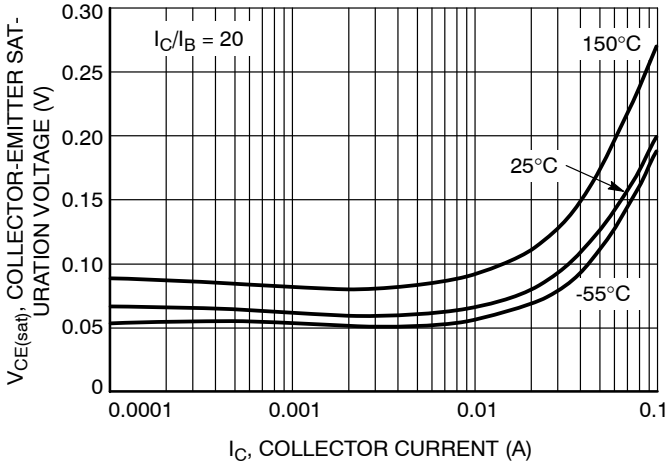

Figure 12. Collector Emitter Saturation Voltage vs. Collector Current

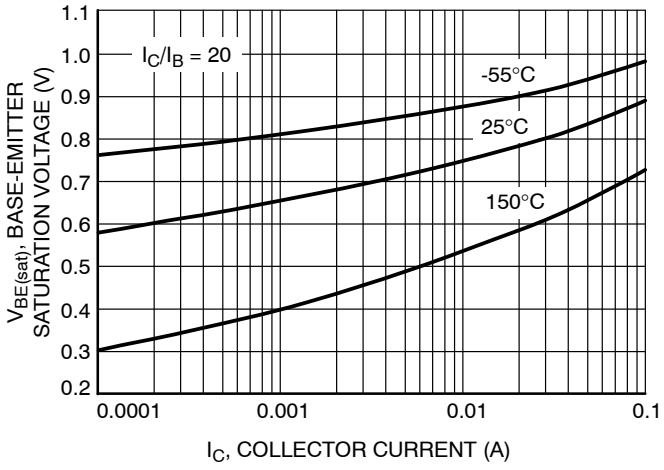

Figure 13. Base Emitter Saturation Voltage vs. Collector Current

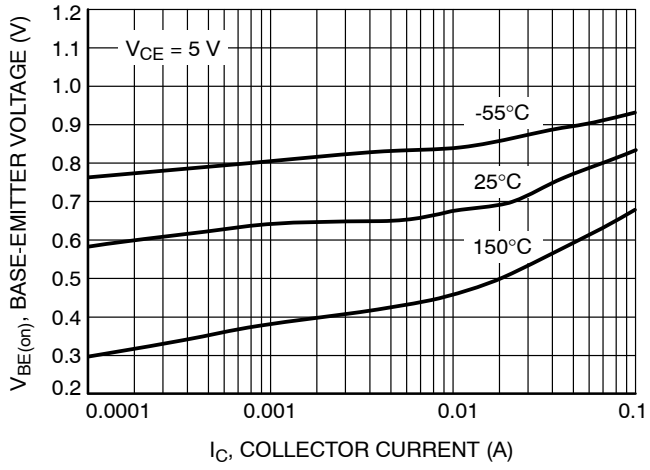

Figure 14. Base Emitter Voltage vs. Collector Current

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BC846B, SBC846B

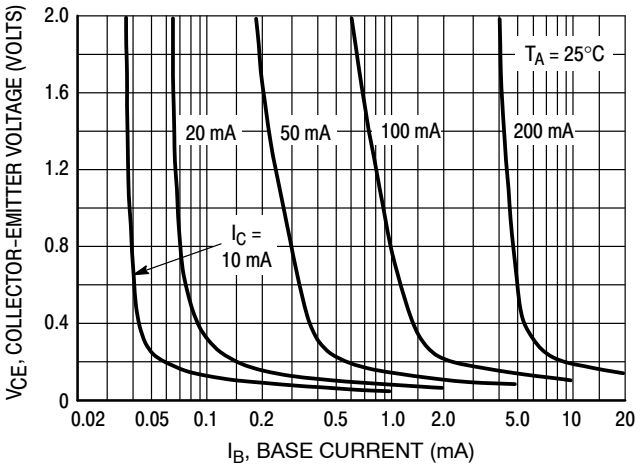

Figure 15. Collector Saturation Region

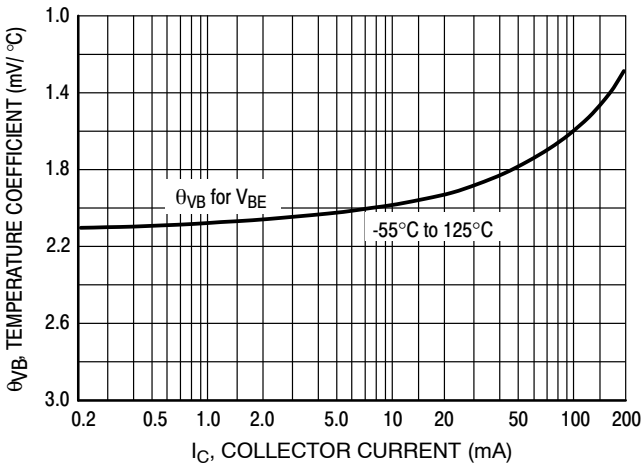

Figure 16. Base-Emitter Temperature Coefficient

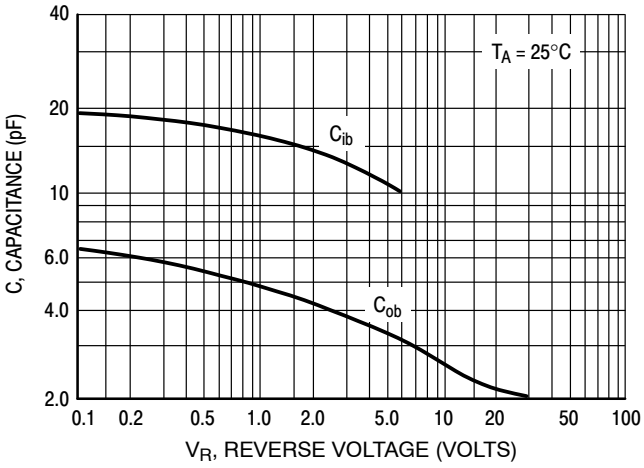

Figure 17. Capacitance

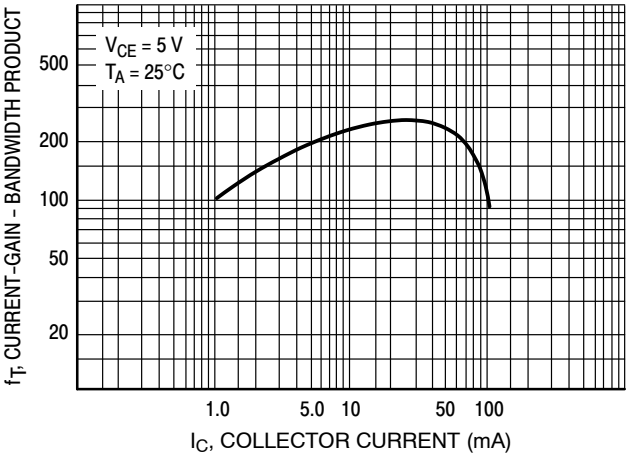

Figure 18. Current-Gain - Bandwidth Product

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BC847B, BC848B, BC849B, BC850B, SBC847B, SBC848B

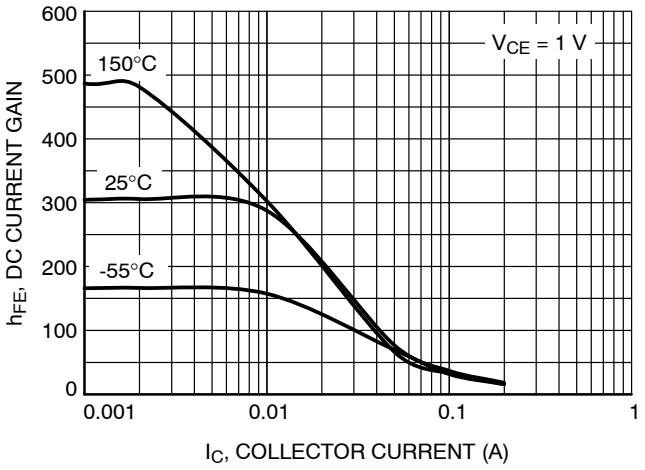

Figure 19. DC Current Gain vs. Collector Current

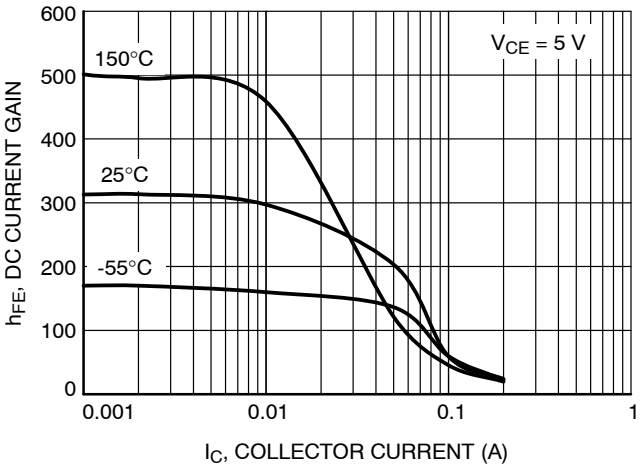

Figure 20. DC Current Gain vs. Collector Current

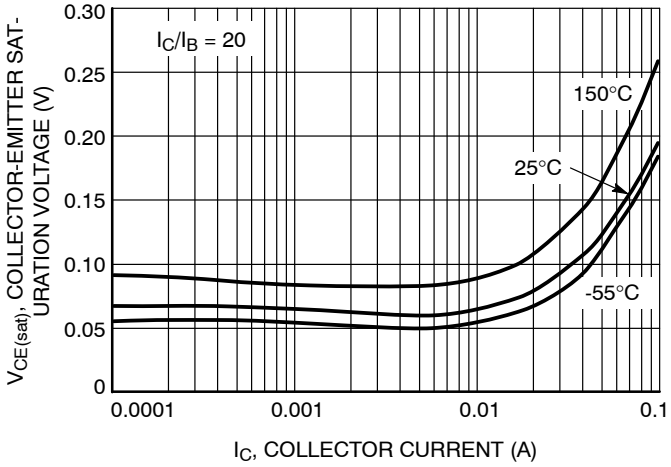

Figure 21. Collector Emitter Saturation Voltage vs. Collector Current

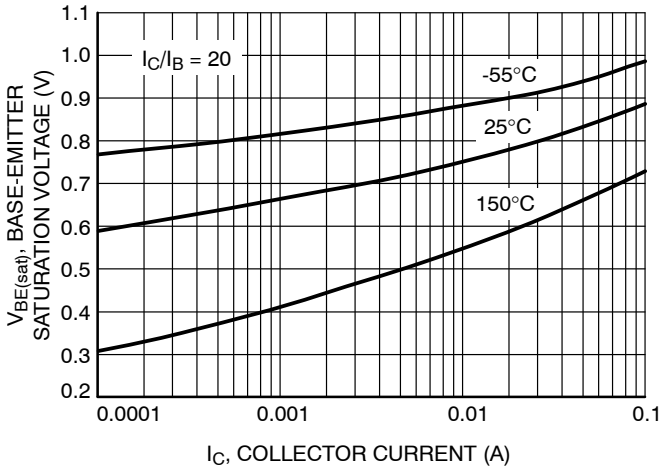

Figure 22. Base Emitter Saturation Voltage vs. Collector Current

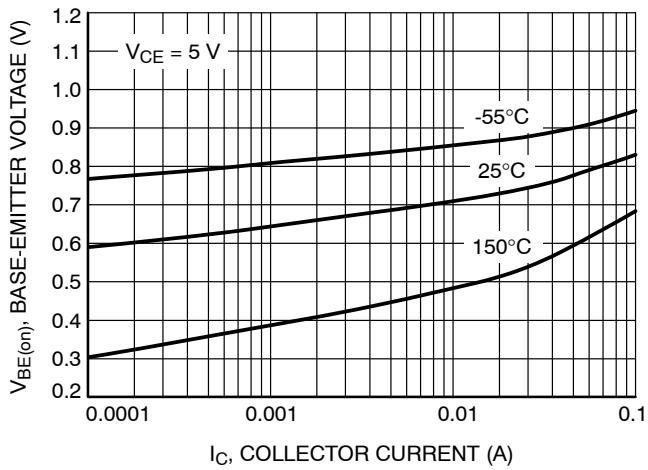

Figure 23. Base Emitter Voltage vs. Collector Current

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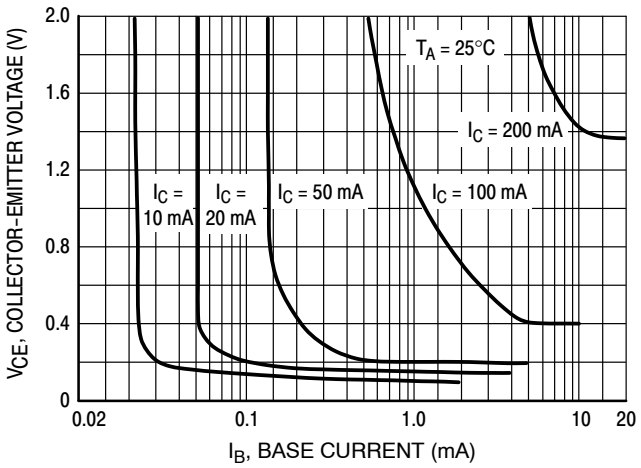

Figure 24. Collector Saturation Region

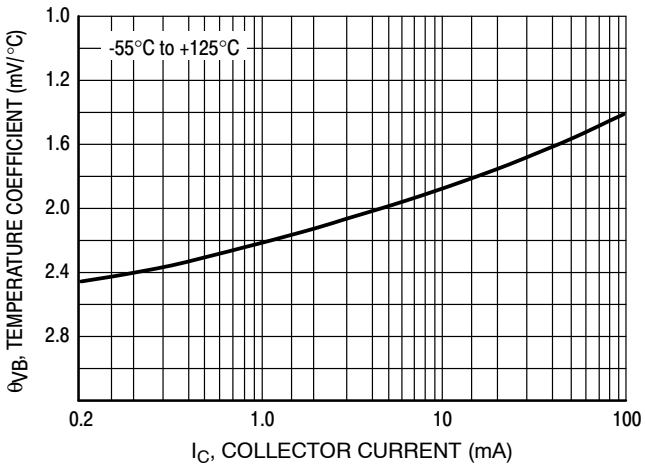

Figure 25. Base-Emitter Temperature Coefficient

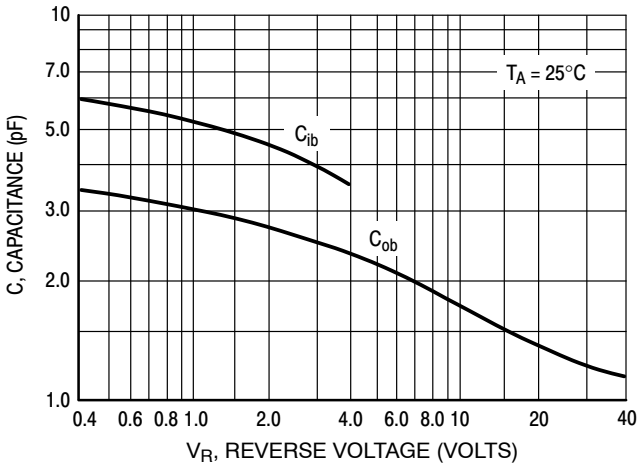

Figure 26. Capacitances

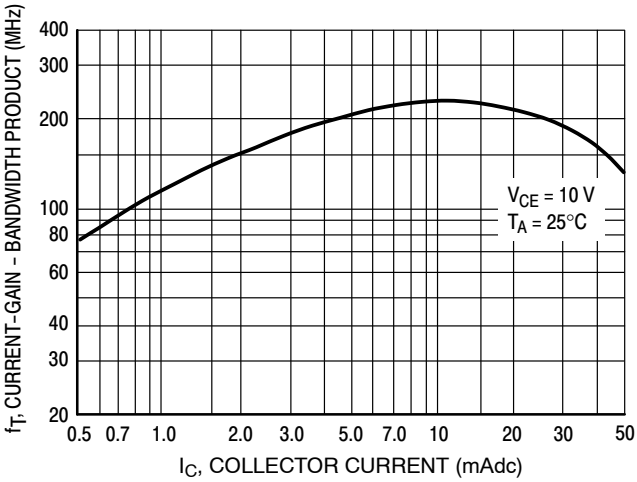

Figure 27. Current-Gain - Bandwidth Product

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BC846C, BC847C, BC848C, BC849C, BC850C, SBC847C

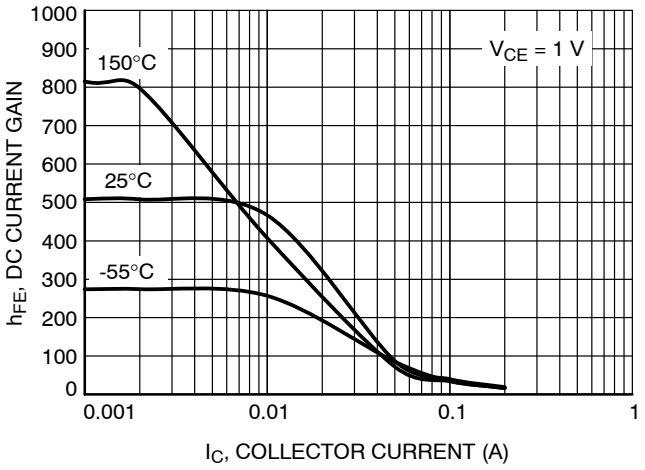

Figure 28. DC Current Gain vs. Collector Current

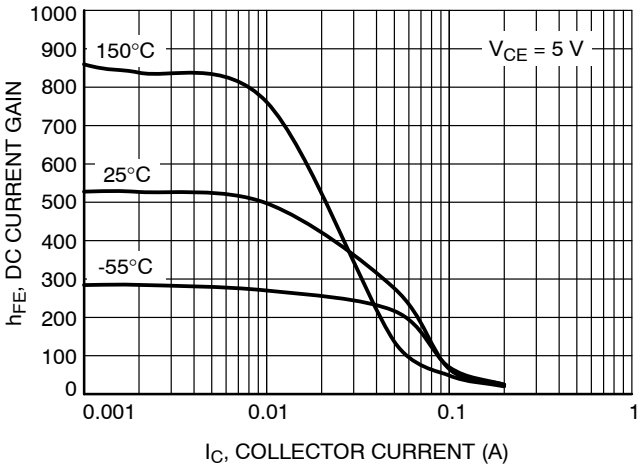

Figure 29. DC Current Gain vs. Collector Current

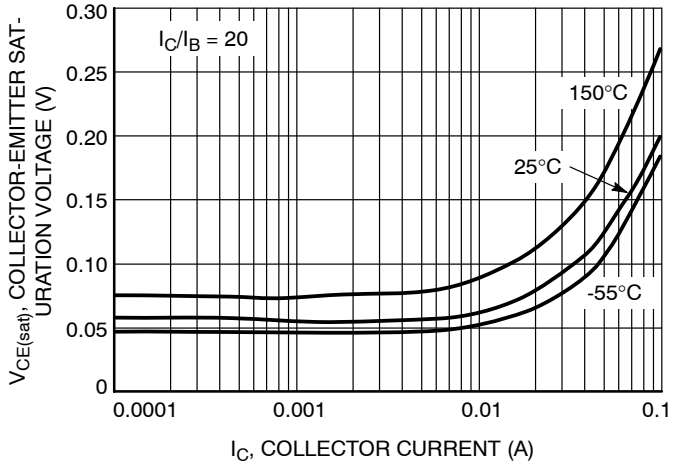

Figure 30. Collector Emitter Saturation Voltage vs. Collector Current

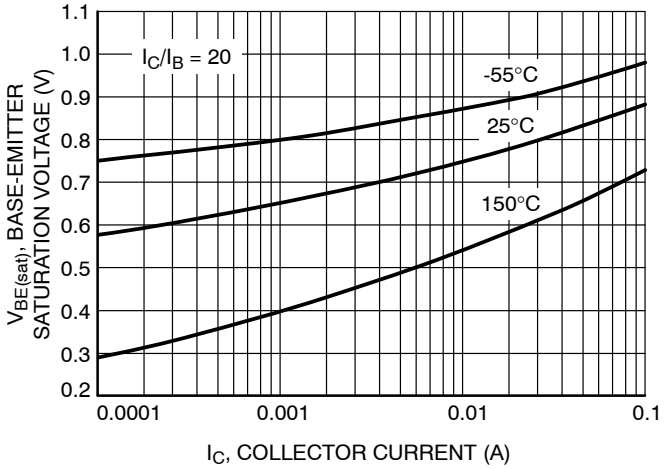

Figure 31. Base Emitter Saturation Voltage vs. Collector Current

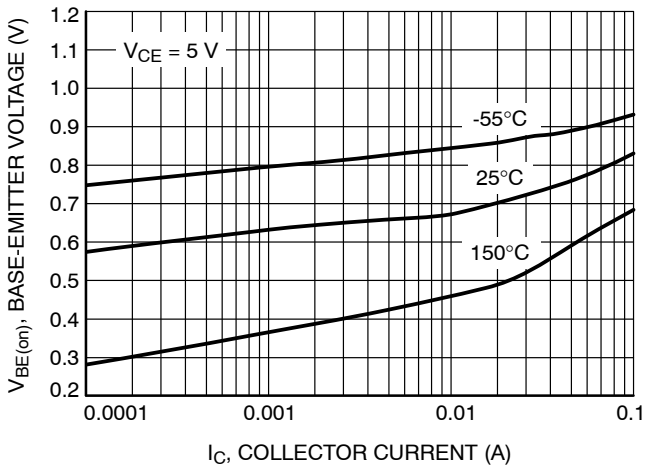

Figure 32. Base Emitter Voltage vs. Collector Current

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BC846C, BC847C, BC848C, BC849C, BC850C, SBC847C

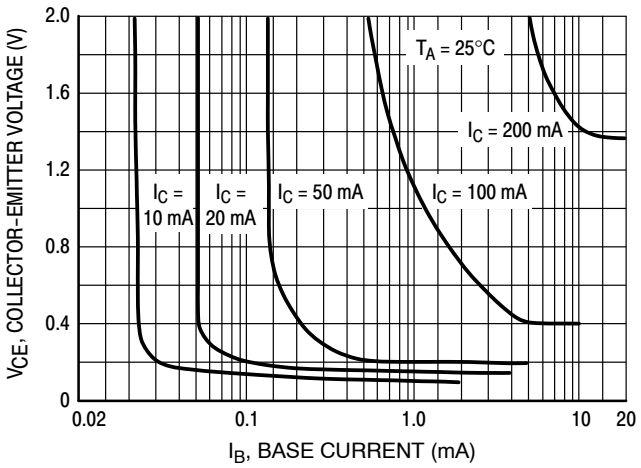

Figure 33. Collector Saturation Region

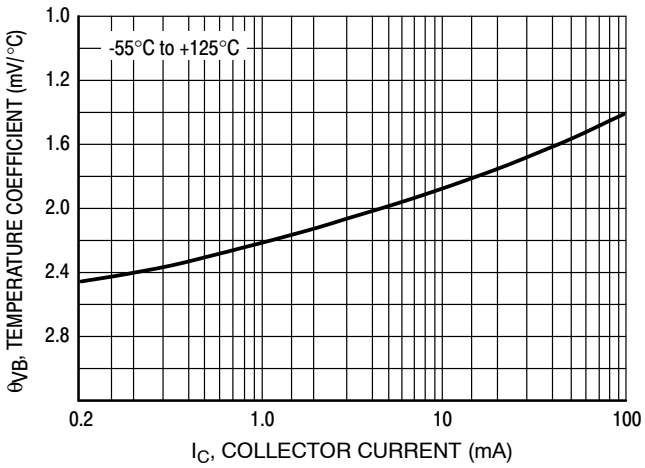

Figure 34. Base-Emitter Temperature Coefficient

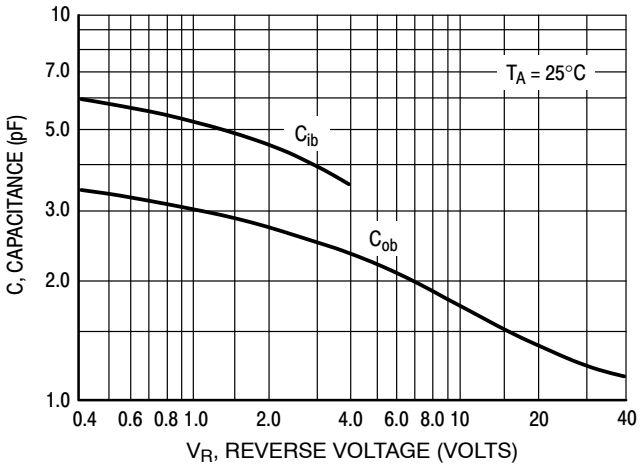

Figure 35. Capacitances

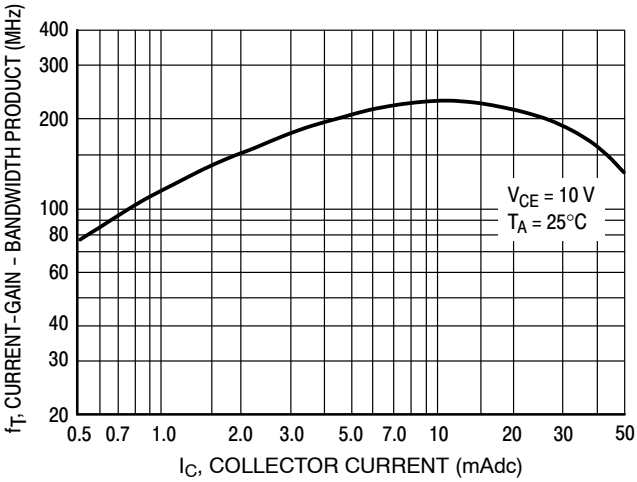

Figure 36. Current-Gain - Bandwidth Product

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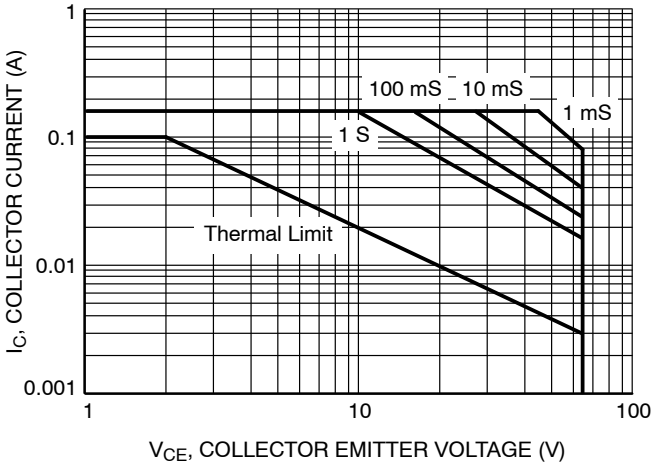

Figure 37. Safe Operating Area for BC846A, BC846B, BC846C

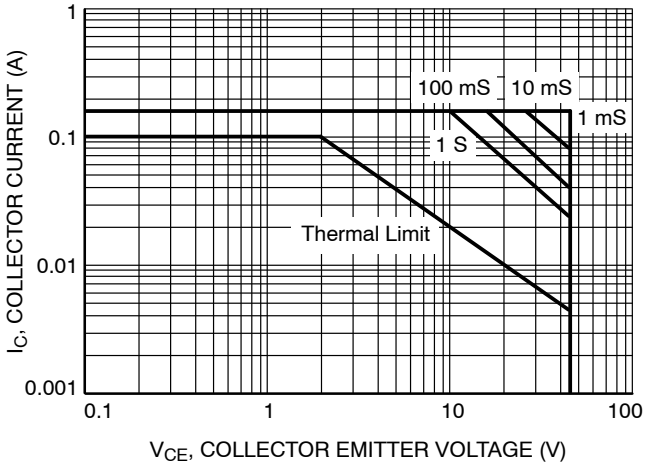

Figure 38. Safe Operating Area for BC847A, BC847B, BC847C, BC850B, BC850C

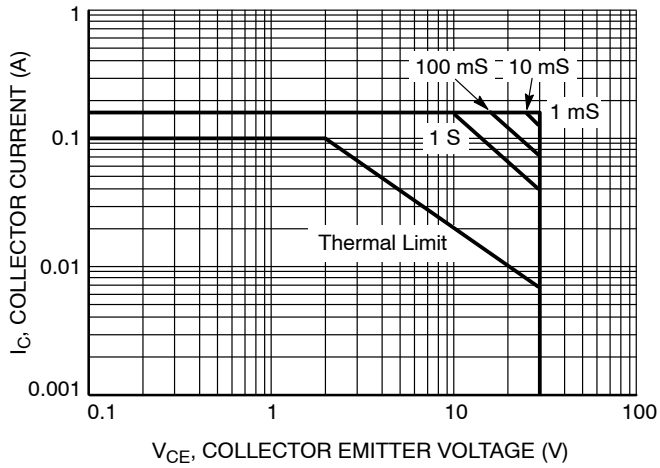

Figure 39. Safe Operating Area for BC848A, BC848B, BC848C, BC849B, BC849C

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ORDERING INFORMATION

Device	Marking	Package	Shipping†
BC846ALT1G BC846ALT1G-NC SBC846ALT1G* SBC846ALT1G-NC*	1A	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC846ALT3G BC846ALT3G-NC			10,000 / Tape & Reel
BC846BLT1G BC846BLT1G-NC SBC846BLT1G* SBC846BLT1G-NC*	1B		3,000 / Tape & Reel
BC846BLT3G BC846BLT3G-NC SBC846BLT3G* SBC846BLT3G-NC*			10,000 / Tape & Reel
BC846CLT1G BC846CLT1G-NC NSVBC846CLT1G*	3C		3,000 / Tape & Reel
BC847ALT1G BC847ALT1G-NC	1E		3,000 / Tape & Reel
BC847BLT1G BC847BLT1G-NC SBC847BLT1G* SBC847BLT1G-NC*	1F		3,000 / Tape & Reel
BC847BLT3G BC847BLT3G-NC NSVBC847BLT3G* NSVBC847BLT3G-NC*			10,000 / Tape & Reel
BC847CLT1G BC847CLT1G−NC SBC847CLT1G* SBC847CLT1G−NC*	1G		3,000 / Tape & Reel
BC847CLT3G BC847CLT3G−NC			10,000 / Tape & Reel
BC848ALT1G BC848ALT1G-NC	1J		3,000 / Tape & Reel
BC848BLT1G BC848BLT1G-NC SBC848BLT1G* SBC848BLT1G-NC*	1K		3,000 / Tape & Reel
BC848BLT3G BC848BLT3G-NC			10,000 / Tape & Reel
BC848CLT1G BC848CLT1G-NC NSVBC848CLT1G* NSVBC848CLT1G-NC*	1L		3,000 / Tape & Reel
BC848CLT3G BC848CLT3G-NC			10,000 / Tape & Reel
BC849BLT1G BC849BLT1G-NC	2B		3,000 / Tape & Reel
BC849CLT1G BC849CLT1G-NC	2C		3,000 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

* S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

3. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

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ORDERING INFORMATION

Device	Marking	Package	Shipping†
BC850BLT1G BC850BLT1G-NC NSVBC850BLT1G* NSVBC850BLT1G-NC*	2F		3,000 / Tape & Reel
BC850CLT1G BC850CLT1G-NC NSVBC850CLT1G* NSVBC850CLT1G-NC*	2G		

DISCONTINUED (Note 3)

BC847ALT3G	1E	SOT-23 (Pb-Free)	10,000 / Tape & Reel
NSVBC849BLT1G*	2B		3,000 / Tape & Reel
BC849BLT3G			10,000 / Tape & Reel
BC849CLT3G	2C		10,000 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

* S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

3. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

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REVISION HISTORY

Revision	Description of Changes	Date
21	Added “–NC” OPNs to order table.	9/2/2026

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

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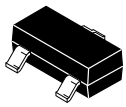
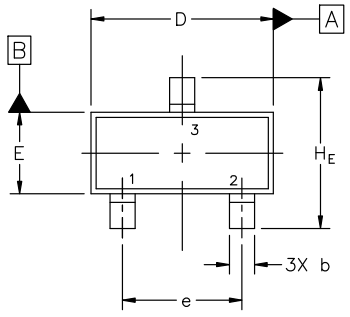


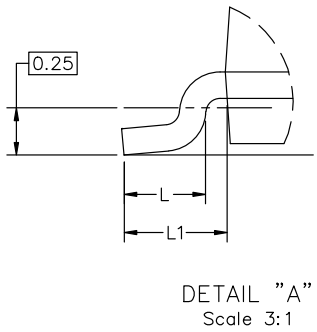
SCALE 4:1

SOT−23 (TO−236) 2.90x1.30x1.00 1.90P
CASE 318
ISSUE AU

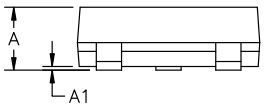
DATE 14 AUG 2024



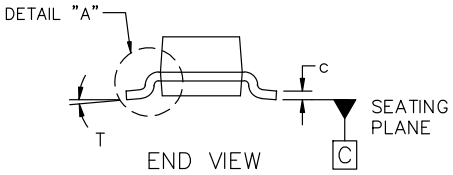
TOP VIEW



DETAIL "A"
Scale 3:1



SIDE VIEW

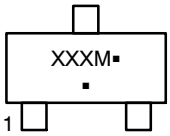


END VIEW

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.89	1.00	1.11
A1	0.01	0.06	0.10
b	0.37	0.44	0.50
c	0.08	0.14	0.20
D	2.80	2.90	3.04
E	1.20	1.30	1.40
e	1.78	1.90	2.04
L	0.30	0.43	0.55
L1	0.35	0.54	0.69
H_E	2.10	2.40	2.64
T	0°	−−−	10°

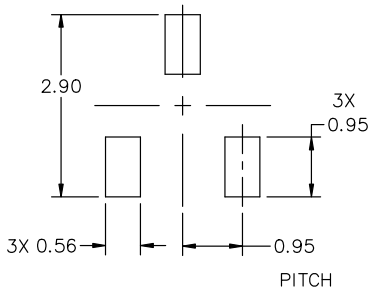
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSIONS: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC
MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



RECOMMENDED
MOUNTING FOOTPRINT

* For additional information on our Pb−Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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CASE 318
ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5:
CANCELLED

STYLE 6:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 7:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 8:
PIN 1. ANODE
2. NO CONNECTION
3. CATHODE

STYLE 9:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 10:
PIN 1. DRAIN
2. SOURCE
3. GATE

STYLE 11:
PIN 1. ANODE
2. CATHODE
3. CATHODE−ANODE

STYLE 12:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 13:
PIN 1. SOURCE
2. DRAIN
3. GATE

STYLE 14:
PIN 1. CATHODE
2. GATE
3. ANODE

STYLE 15:
PIN 1. GATE
2. CATHODE
3. ANODE

STYLE 16:
PIN 1. ANODE
2. CATHODE
3. CATHODE

STYLE 17:
PIN 1. NO CONNECTION
2. ANODE
3. CATHODE

STYLE 18:
PIN 1. NO CONNECTION
2. CATHODE
3. ANODE

STYLE 19:
PIN 1. CATHODE
2. ANODE
3. CATHODE−ANODE

STYLE 20:
PIN 1. CATHODE
2. ANODE
3. GATE

STYLE 21:
PIN 1. GATE
2. SOURCE
3. DRAIN

STYLE 22:
PIN 1. RETURN
2. OUTPUT
3. INPUT

STYLE 23:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 24:
PIN 1. GATE
2. DRAIN
3. SOURCE

STYLE 25:
PIN 1. ANODE
2. CATHODE
3. GATE

STYLE 26:
PIN 1. CATHODE
2. ANODE
3. NO CONNECTION

STYLE 27:
PIN 1. CATHODE
2. CATHODE
3. CATHODE

STYLE 28:
PIN 1. ANODE
2. ANODE
3. ANODE

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